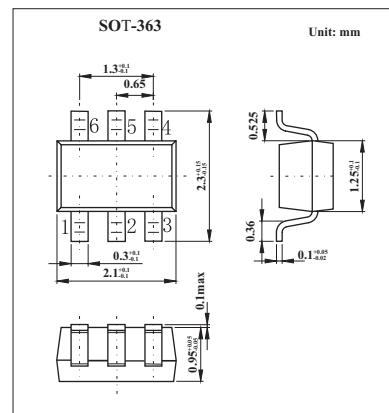
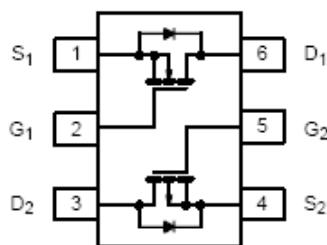


## Complementary 20-V (D-S) MOSFET

### KI1553DL

#### ■ PIN Configuration



#### ■ Absolute Maximum Ratings $T_A = 25^\circ\text{C}$

| Parameter  | Symbol         | N-Channel  |              | P-Channel  |              | Unit |
|--|----------------|------------|--------------|------------|--------------|------|
|  |                | 5 secs     | Steady State | 5 secs     | Steady State |      |
| Drain-Source Voltage   | $V_{DS}$       | 20         |              | -20        |              | V    |
| Gate-Source Voltage  | $V_{GS}$       | $\pm 12$   |              |            |              | V    |
| Continuous Drain Current ( $T_J = 150^\circ\text{C}$ )* $T_A = 25^\circ\text{C}$ | $I_D$          | $\pm 0.7$  | $\pm 0.66$   | $\pm 0.44$ | $\pm 0.41$   | A    |
|  |                | $\pm 0.5$  | $\pm 0.48$   | $\pm 0.31$ | $\pm 0.3$    | A    |
| Pulsed Drain Current   | $I_{DM}$       | $\pm 1.0$  |              |            |              | A    |
| Continuous Source Current (Diode Conduction)a                                    | $I_S$          | 0.25       | 0.23         | -0.25      | -0.23        | A    |
| Maximum Power Dissipation* $T_A = 25^\circ\text{C}$                              | $P_D$          | 0.3        | 0.27         | 0.3        | 0.27         | W    |
|  |                | 0.16       | 0.14         | 0.16       | 0.14         | W    |
| Operating Junction and Storage Temperature Range                                 | $T_J, T_{STG}$ | -55 to 150 |              |            |              | °C   |

\*Surface Mounted on 1" X 1" FR4 Board.

#### ■ Thermal Resistance Ratings $T_A = 25^\circ\text{C}$

| Parameter                        |                        | Symbol     | Typical | Maximum | Unit |
|----------------------------------|------------------------|------------|---------|---------|------|
| Maximum Junction-to-Ambient*     | $t \leq 5 \text{ sec}$ | $R_{thJA}$ | 360     | 415     | °C/W |
|                                  | Steady State           |            | 400     | 460     |      |
| Maximum Junction-to-Foot (Drain) | Steady State           | $R_{thJF}$ | 300     | 350     |      |

\*Surface Mounted on 1" X 1" FR4 Board.

**KI1553DL**■ Electrical Characteristics  $T_J = 25^\circ\text{C}$ 

| Parameter                          | Symbol              | Testconditons   |      | Min  | Typ   | Max       | Unit          |
|------------------------------------|---------------------|---|------|------|-------|-----------|---------------|
| Gate Threshold Voltage             | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$  | N-Ch | 0.6  |       |           | V             |
|                                    |                     | $V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$   | P-Ch | -0.6 |       |           |               |
| Gate Body Leakage                  | $I_{GSS}$           | $V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 12\text{V}$  | N-Ch |      |       | $\pm 100$ | nA            |
| Zero Gate Voltage Drain Current    | $I_{DSS}$           | $V_{DS} = 16 \text{ V}$ , $V_{GS} = 0 \text{ V}$  | N-Ch |      |       | 1         |               |
|                                    |                     | $V_{DS} = -16 \text{ V}$ , $V_{GS} = 0 \text{ V}$   | P-Ch |      |       | -1        |               |
|                                    |                     | $V_{DS} = 16 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 85^\circ\text{C}$   | N-Ch |      |       | 5         | $\mu\text{A}$ |
|                                    |                     | $V_{DS} = -16 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 85^\circ\text{C}$  | P-Ch |      |       | -5        |               |
| On State Drain Currenta            | $I_{D(on)}$         | $V_{DS} \geq 5 \text{ V}$ , $V_{GS} = 4.5 \text{ V}$  | N-Ch | 0.6  |       |           | A             |
|                                    |                     | $V_{DS} \leq -5 \text{ V}$ , $V_{GS} = -4.5 \text{ V}$  | P-Ch | -1.0 |       |           |               |
| Drain Source On State Resistance*  | $r_{DS(on)}$        | $V_{GS} = 4.5 \text{ V}$ , $I_D = 0.66\text{A}$   | N-Ch |      | 0.320 | 0.385     | $\Omega$      |
|                                    |                     | $V_{GS} = -4.5 \text{ V}$ , $I_D = -0.41\text{A}$   | P-Ch |      | 0.850 | 0.995     |               |
|                                    |                     | $V_{GS} = 2.5 \text{ V}$ , $I_D = 0.40\text{A}$   | N-Ch |      | 0.560 | 0.630     |               |
|                                    |                     | $V_{GS} = -2.5 \text{ V}$ , $I_D = -0.25\text{A}$   | P-Ch |      | 1.4   | 1.800     |               |
| Forward Transconductance*          | $g_{fs}$            | $V_{DS} = 10 \text{ V}$ , $I_D = 0.66\text{A}$  | N-Ch |      | 1.5   |           | mS            |
|                                    |                     | $V_{DS} = -10 \text{ V}$ , $I_D = -0.41\text{A}$  | P-Ch |      | 0.8   |           |               |
| Diode Forward Voltage*             | $V_{SD}$            | $I_S = 0.23\text{A}$ , $V_{GS} = 0 \text{ V}$   | N-Ch |      | 0.8   | 1.2       | V             |
|                                    |                     | $I_S = -0.23\text{A}$ , $V_{GS} = 0 \text{ V}$  | P-Ch |      | -0.8  | -1.2      |               |
| Total Gate Charge                  | $Q_g$               | N-Channel<br>$V_{DS} = 10 \text{ V}$ , $V_{GS} = 4.5 \text{ V}$ , $I_D = 0.66\text{A}$  | N-Ch |      | 0.8   | 1.2       | pC            |
| Gate Source Charge                 | $Q_{gs}$            |   | P-Ch |      | 1.2   | 1.8       |               |
| Gate Drain Charge                  | $Q_{gd}$            |   | N-Ch |      | 0.06  |           |               |
| Turn On Time                       | $t_{d(on)}$         | P-Channel<br>$V_{DD} = -10 \text{ V}$ , $R_L = 20 \Omega$<br>$I_D = 0.5 \text{ A}$ , $V_{GEN} = 4.5\text{V}$ , $R_g = 6 \Omega$ | P-Ch |      | 0.45  |           |               |
|                                    | $t_r$               |   | N-Ch |      | 10    | 20        | ns            |
| Rise Time                          |                     |   | P-Ch |      | 7.5   | 15        |               |
| Turn Off Delay Time                | $t_{d(off)}$        |   | N-Ch |      | 16    | 30        |               |
|                                    | $t_f$               |   | P-Ch |      | 20    | 40        |               |
| Fall Time                          |                     |   | N-Ch |      | 10    | 20        |               |
| Source-Drain Reverse Recovery Time | $t_{rr}$            | $I_F = 0.23 \text{ A}$ , $dI/dt = 100 \text{ A}/\mu\text{s}$  | P-Ch |      | 8.5   | 17        |               |
|                                    |                     | $I_F = -0.23 \text{ A}$ , $dI/dt = 100 \text{ A}/\mu\text{s}$   | N-Ch |      | 12    | 24        |               |
|                                    |                     |   | P-Ch |      | 25    | 40        |               |

\* Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .